Fabrication and superconductivity of Na_xTaS₂ crystals

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In this paper we report the growth and superconductivity of N a_x T aS_2 crystals. The structural data deduced from X-ray diraction pattern shows that the sample has the same structure as TaS_2 . A series of crystals with di erent superconducting transition tem peratures (T_c) ranging 2H from 2.5 K to 4.4 K were obtained. It is found that the $T_{\rm c}$ rises with the increase of N a content determ ined by Energy-D ispersive x-ray m icroanalysis (EDX) of Scanning E lectron M icroscope (SEM) on these crystals. C om pared with the resistivity curve of un-intercalated sam ple 2H TaS_2 ($T_c =$ 70 K), no signal of charge density wave (CDW) was observed in samples N $a_{0:1}\,T\,aS_2$ 0.8 K, TCDW and N $a_{0:05}$ T aS₂. However, in some samples with lower T_c, the CDW appears again at about 65 K. Comparison between the anisotropic resistivity indicates that the anisotropy becom es smaller in samples with more N a intercalation (albeit a weak sem iconducting behavior along c-axis) and thus higher T_c . It is thus concluded that there is a competition between the superconductivity and the CDW . With the increase of sodium content, the rise of T_c in N a_x T aS_2 is caused mainly by the suppression to the CDW in 2H TaS_2 , and the conventional rigid band m odel for layered dichalcogenide may be inadequate to explain the changes induced by the slight intercalation of sodium in 2H TaS_2 .

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I. IN TRODUCTION

Layered transition-m etal dichalcogenides (TMDC's) of the type M X₂ (M is the transition metal, X = S, Se, Te) have been extensively studied for their rich electronic properties due to low dim ensionality. Each layer of TMDC's consists of a hexagonal transition m etal sheet sandwiched by two sim ilar chalcogen sheets, the interaction between the M X₂ layers is weak and van der W aals-like. Charge density wave (CDW) and superconductivity (SC) coexist in this kind of materials. The electron-phonon coupling and its relationship with the CDW are investigated by angle resolved photoem ission in T as e_2 and 2H N bs e_2 system s¹. It is found that 2H the CDW transition temperature decreases and meanwhile the superconducting critical tem perature (T_c) increases from $TaSe_2$ through TaS_2 and $NbSe_2$ to NbS_2 , which indicates that these two orders (CDW and superconductivity) com pete each other^{2,3}.

Intercalation of atom s and m olecules into the weak coupled region between the M X₂ layers leads to significant m odi cation of properties, which is another highlight to study TM DC's. A variety of atom s and m olecules were reported to be intercalated into the interlayer regions between the M X₂ layers, and the resulting com – pounds are superconducting⁴. Furtherm ore, di erent superconducting transition tem peratures T_c were found depending on the intercalated 1 M D C's were further hydrated⁷. The change of properties induced by intercalation m ay be explained in terms of charge transfer from the intercalated atom s or m olecules to the host M X₂ layers, the band structure is unaltered upon intercalation, and den-

sity of states (DOS) at Ferm isurface (FS) changes to reect the transfer of charges from the intercalated atoms or molecules. This picture is called as the rigid-band model (RBM). The validity of this model is supported by some photoem ission experiments and calculations for various intercalates of M X $_2^{8,9,10,11}$.

In recent years, however, som e experiments and calculations revealed that the change of properties of the intercalated M X₂ cannot be understood based on the rigid-band model. The electrical measurement of TaS_2 (pyridine)₁₌₂ showed that there was no signal of CDW in the resistivity curve, which was attributed to the suppression of a structural instability by intercalation¹². Angle-resolved photoem ission was used to study the electronic band structures before and after the alkaline m etal Cs and N a were intercalated into the 2H $TaSe_2$ and $VSe_2^{13,14,15}$, and it was found that the changes induced by intercalation was more extensive than that expected by the rigid-band m odel. The experim ent of N a intercalation into 1T TaS2 also revealed that the properties of the CDW phases and the phase transitions are not only in uenced by the shift of the Ferm i-level in the Ta 5d band, but also by the superstructure of the doped N a in the interlayer region¹⁶.

Therefore, it remains controversial whether it is possible to use the rigid-band model to explain the changes induced by the intercalation in TMDC's. In order to unravel this puzzle, more e orts are desired. In the family of TMDC's, the sample TaS_2 may be one of the model systems to tackle this problem. Two basic structures of TaS_2 were found and de ned by the diment orientation of stacking chalcogen sheets, one is $1T TaS_2$ with Ta in octahedral coordination with S atoms, another is $2H TaS_2$ with Ta in trigonal-prism atic coordination.

tion with S atom s^{17,18}. The system 1T TaS_2 shows four CDW phase transitions accompanied by changes in lattice parameters and resistivity when temperature decreases, the CDW form ation could be explained by the Ferm i surface nesting^{16,17,19}. However, the system 2H TaS₂ is known for the existence of CDW order below 70 K and a superconducting transition at 0.8 K 17,19 . W hen sodium ions are intercalated into 2H TaS_2, T_c increases. Poly-crystalline samples of N $a_{0:33}TaS_2$ were made and reported to be superconductors below 4.7 K $(T_c^{on eset})^{5,6}$, and the T_c was increased to 5.5 K when the samples were hydrated⁷. In this paper, we report the growth of a series of crystals of N $a_x T a S_2$ (2H) with di erent superconducting transition tem peratures. M easurem ents of X-ray di raction and superconducting transition revealed good quality of these crystals.

II. EXPERIMENT

Most layered compounds are known to intercalate atom s or m olecules into the inter-layer regions. A traditional way for fabricating intercalated layered dichalcogend compounds consists of two steps, the rst step is to prepare poly-crystalline compound or single crystal of M X₂ by chem ical reaction or iodine-transport reaction^{7,20}; Secondly, the intercalation is carried out by chem icaltreatm ents, the sam ples are dipped into concentrated solutions containing the intercalated atom s^{7,16,20}, or exposed to m etal vapors in a closed am poule¹⁶. A new method suited for preparing samples for the studies of surface science was also reported, the intercalated com pounds were prepared by in situ evaporation of metal atom s to the (0 0 0 1) cleaved surface of the TMDC's crystals. This process should be realized under the condition of ultra high vacuum (UHV)^{14,21}.

In this paper, we report the growth of crystals of $N a_x T a S_2$ directly with chemical reaction. The starting materials are N aC l, T a powder and sulfur powder with purity higher than 99:9%. The nom inal mole ratio of N aC L, T a, and S were 0.15, 1 and 2, respectively. They were mixed and thoroughly ground, then pressed into pellet, nally the pellet was sealed in an evacuated quartz tube. The tube was heated slow ly up to 920 C and sintered for 48 hours, then slow ly cooled down to 700 C with a cooling rate of 1 2 C=hr. Finally the quartz tube was cooled down with furnace by shutting o the power. It is found that two kinds of crystals were obtained. A large number of black thin platelets grew on the inner side of the quartz tube. The surfaces of these platelets were rather wrinkled, but the subsequent AC diam agnetism measurement showed that these crystals had weak diam agnetic signal and broad transition. Another type of crystals were also black thin platelets which grew vertically on the surface of the pellet. The surface of the second kind of crystals was shiny and m irror-like, but the number of them is quite limited. Subsequent X ray di raction pattern and AC diam agnetic m easurem ent

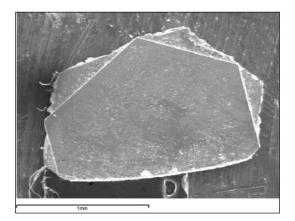


FIG.1: An enlarged view of the N $a_{0:1}TaS_2$ crystal. The intercalated sodium content is determ ined by Energy D ispersive x-ray M icroanalysis (EDX) of SEM.

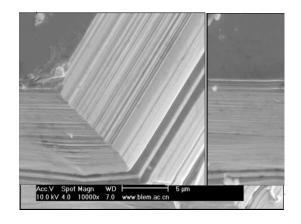


FIG.2: An enlarged view of the N $a_{0:1}TaS_2$ crystal at a corner. It is obvious that the sam ples have layered structure.

showed that this kind of crystal has the typical structure of 2H $_{\rm T}$ aS $_{\rm 2}$ single crystal and sharp superconducting transition is observed on them . It is found that the size and the superconducting transition temperature of the second type of crystals are related to the cooling rate.

Fig. 1 shows an enlarged view of one piece of N $a_{0:1}TaS_2$ crystals. The crystal is shiny and thin platelet-like with clean and smooth surface. The dimension of the crystal is about 1.7 1 mm² and the thickness is about 0.1mm. Fig. 2 shows an enlarged view of the N $a_{0:1}TaS_2$ crystal at a corner. It is clear that the sample has a layered structure.

The x-ray di raction pattern was performed at room temperature employing a M 18AHF x-ray di ractometer (MAC Science). Crystallographic orientation and index are determined by Power-X, a programm for processing X-ray di raction data²². The magnetic and transport m easurements were carried out with an 0×1 multiparameter measurement system (M aglab-Exa-12). The in-plane resistivity was determined by using standard four point measurement. The o -plane resistivity was measured by putting two separate pads of silver paste (one larger one for current and smaller one for voltage) on both sides of the sample. Since the in-plane resistivity is much smaller than the o -plane one, the whole area of the sample plane was taken as the cross-section area of the current owing along c-aixs in determining c. The microscopic and concentration analysis is achieved with Energy D ispersive x-ray Microanalysis (EDX) of scanning electron microscope (O xford).

III. RESULTS AND DISCUSSION

A. Structure and X -ray di raction

Fig.3 presents the X-ray di raction pattern at room tem perature for one N $a_x T a S_2$ crystal. The XRD pattem is indexed on the basis of hexagonal with c =12:082A, the value is quite close to the reported value $c = 12.070A^{23}$ and $c = 12.097A^{18}of2H$ TaS_2 . Further comparison with the value of N $a_{0:8}$ T aS_2 (c = 14:36A) indicates that only little content of sodium ions are intercalated into the inter-layer regions of 2H TaS₂ in our present sam ples. The space group is P 6m 2, which is TaS_2 (P6₃/mmc). For more Na the subgroup of 2H intercalated samples, the main peaks remain unshifted and sharp, no obvious change of the c axis constant has been observed, but som e com m ensurate m odulation peaks around each main peak along c-axis appear. Detailed analysis about these modulations will be presented in a forthcoming paper. Although the di raction pattern is quite clean and the full-width at the half maximum (FW HM) of the di raction peak is narrow, we cannot, however, rule out the possibility of some kind of stacking fault which often appear in the intercalated crystals. Howeverwewould argue that the stacking fault could be weak in our present case since only very little sodium are intercalated into the structure. Furtherm ore it rem ains unknown whether the intercalated sodium atoms are in disordered state or organize into an ordered lattice.

B. AC diam agnetism and EDX of SEM

It is found that both the T_c and size of crystal are related to the cooling rate. Fig. 4 shows four superconducting transition curves of four sam ples. The T_c determined in the diam agnetic measurem ent changes from 4.4 K to 3.0 K, which is de ned by the onset point of the real part of AC susceptibility. The transition width of each curve is less than 0.5 K, which indicates a complete M eissner shielding e ect. Because the biggest crystal has the highest T_c , it is natural to suppose that the increase of T_c is related to the change of sodium content, which is

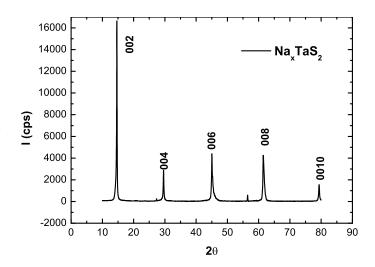


FIG.3: X -ray di raction pattern of a N $a_x T a S_2$ crystal. The c-axis lattice constant determ ined here is about c = 12.082A which is quite close to that of 2H $T a S_2$. W ith increasing the N a content no obvious change of the c axis constant has been observed in our samples.

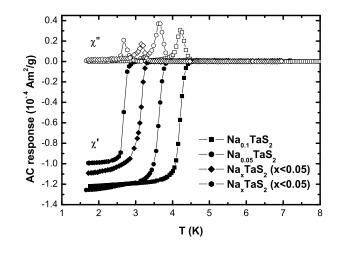


FIG.4: AC diamagnetism ($H_{AC} = 10e; f = 333Hz$) for a series of N $a_x T aS_2$ crystals. A nalysis using EDX reveals that the sodium content are slight di erent among the sam ples.

controlled by the time and extent of di usion. In order to know the sodium content, these crystals were analyzed with the EDX of SEM . Taking account of the possible inhom ogeneity existing in the sam ples, we selected multiple points on each crystal surface and analyzed. The EDX spectrum showed that the atom ic concentration of di erent analyzed regions were similar, which indicates that these crystals are hom ogeneous. Table-I gives sodium content of crystals analyzed by EDX of SEM . T_c rises roughly with the increase of N a content in these crystals. As to the crystals with T_c equal to 3.4 K and 3.0 K, respectively, little sodium ions are detected by EDX.

TABLE I:Sodium extent intercalated into $2H\mathchar`-TaS_2$ analyzed by EDX of SEM .

Тс	Atomic % (Na:Ta)	Formula
4.4 K	2.62 : 27.09	Na _{0:1} TaS ₂
4 . 0 K	1.22 : 25.90	$Na_{0:05}TaS_2$
3 . 4 K	sodium % < 1	$N a_x T a S_2$ (0< x< 0.05)
3 . 0 K	sodium % < 1	$Na_{x}TaS_{2}$ (0< x< 0.05)

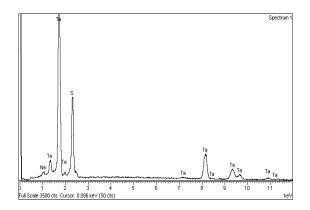


FIG. 5: EDX spectrum of the N $a_{0:05}TaS_2$ crystal. The characteristic peak of sodium around 1.1 keV is obvious.

B ecause the $T_{\rm c}$ of 2H $\,$ T aS_2 is 0.8 K , thus, the sodium content in these two crystals are approximately between 0 and 0.05.

Fig.5 shows the EDX spectrum of N $a_{0:05}TaS_2$ crystal. The characteristic peak of sodium around 1.1 keV is obvious. No signal of chlorine ions appears in the spectrum. The spectrum of N $a_{0:1}TaS_2$ crystal is similar to that of N $a_{0:05}TaS_2$ crystal, but the peak of sodium gets enhanced for the form er.

It is generally believed that superconductivity in the dichalcogenides is due to electron-phonon coupling and is of conventional BCS type. A coording to BCS theory, T_c rises when the density of states at Ferm i surface is increased, which is inferred by the following form ula,

$$T_{c} / D_{p} \exp[1=VN(E_{F})]$$
(1)

where $_{\rm D}$ is the D ebye tem perature, V is the electron-electron interaction which consists of the attractive electron-phonon-induced interaction subtracted by the repulsive C oulom b interaction, and N (E $_{\rm F}$) is the density of states at Ferm i surface. As to our know ledge, change of V was rarely reported when atom s or m olecules are intercalated into TM DC's. G ample et al.⁴ pointed out that the electron-phonon interaction is con ned to the m etallic disul de layers and insensitive to the distance

between M X $_2$ layers caused by intercalation. Thus, on the basis of little change of electron-phonon interaction, it is considered that N (E $_{\rm F}$) plays an important role for the increase of $T_{\rm c}$ in N a_x T aS_2 .

Calculations of DOS for the conduction band of 2H TaS_2 showed that E_F lies approximately at the midpoint of the d_{z^2} band of T a, and the d_{z^2} band is half led (occupied by one electron per form ula unit) and the DOS has a peak at the Ferm i level^{9,10}. When sodium ions are intercalated between the layers of 2H TaS_2 , charges are transferred from sodium to d_{z^2} band of Ta. The rigid-band m odel of intercalation suggests that the host band structure is unaltered upon intercalation, with $E_{\rm F}$ increasing to re ect the transfer of charges from the intercalant. Consequently the DOS at Ferm i surface should decrease. This is in contradiction to the observation that the T_c increases instead of decreasing when the sodium atom sare intercalated. W ewill show below that the DOS at Ferm i levelm ay increase because of the suppression to the CDW, rather due to the charge transfer.

C. The Anisotropy of the Upper Critical Field

As to our knowledge, the upper critical eld $H_{c2}(0)$ of N $a_x T a S_2$ was rarely reported. We studied $H_{c2}(0)$ of one piece crystal of N $a_{0:1}T a S_2$ with $T_c = 4.3$ K through diam agnetic and transport m easurem ent. Fig.6 presents the AC susceptibility under di erent magnetic elds. The transition curve m oves regularly down to low er tem peratures with increasing the magnetic eld. Since the vortex m otion is involved in the AC susceptibility measurem ent, it is di cult to de ne the onset point for superconductivity. Therefore in the following we will use resistive transport m easurem ent to determ ine the upper critical eld.

Fig.7 shows the in-plane resistivity (ab plane) of the crystalN $a_{0:1}TaS_2$ at zero edd. Decreasing temperature from 10K to 4:9K, the resistivity changes subtly, and an abrupt superconducting transition happens at 4:83K, zero resistivity is obtained at about 4:3K. A sharp transition with width less than 0.5K indicates the good quality of the crystalN $a_{0:1}TaS_2$. The zero superconducting transition temperature is 4:3K, which is consistent with the result of AC susceptibility.

In order to determ ine the upper critical eld and the anisotropy of superconductivity, we measured the resistive transitions at di erent magnetic elds with the

led direction along ab plane (Fig.8(a)) and c axis (Fig.8(b)). One can see that the resistive curve shifts parallel down to lower temperatures with the increase of magnetic eld. From the mid-point of the transition curves, we determ ine the upper critical elds for both directions which are shown in Fig.9. In the G inzburg-Landau theory, it is known that $H_{c2} = _0=2^{-2}$ and

/ $(1 + t^2) = (1 t^2)$, with $_0$ the ux quanta, the coherence length, $t = T = T_c$ the reduced temperature, thus one has

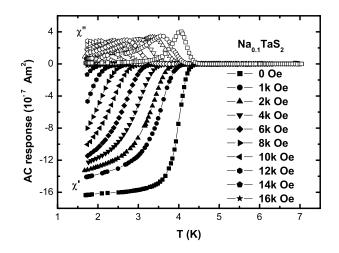


FIG.6: AC susceptibility ($H_{AC} = 10 \text{ e;} f = 333 \text{ Hz}$) under dierent DC magnetic elds for the crystal N a_{0:1}T aS₂. Here the DC magnetic eld is applied along c-axis.

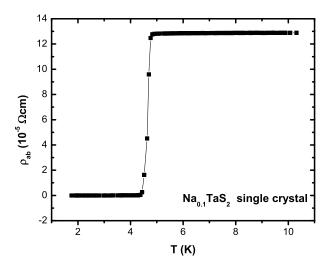


FIG.7: In-plane resistivity (ab plane) vs. tem perature for one piece of crystal N $a_{0:1}TaS_2$ under zero eld. The transition width is less than 0.5 K.

$$H_{c2}(T) = H_{c2}(0) \frac{1 t^2}{1 + t^2}$$
 (2)

We use above equation to t our data and show them as the solid and dashed lines in Fig.9. The zero temperature upper critical elds $H_{c2}(0)$ determined in this way are $H_{c2}^{jic}(0) = 2.5T$ and $H_{c2}^{jiab}(0) = 16T$, therefore the anisotropy

6 5 H||ab -D- OT 4 0 1T R_{ab}(mΩ) 2T 3Т 3 4T – 5T 4 2 - 6T - 1> -O— 8T -☆— 10T 1 ·Ô− 12T (a) 0 6 5 H||c 公-公-公 0T R_{ab}(mΩ) 4 -O-0.1T -∆— 0.2T -∇— 0.4T 3 - 0.61 0-0-0-00 ⊲−0.8T \triangleright - 1T Ϋ́ 2 O- 1.2T ☆— 1.4T -�— 1.6T 1 -©— 1.8T (b) +— 2T 0 2 3 5 6 1 4 7 8 T(K)

FIG.8: The superconducting transition m easured at di erent magnetic elds when the eld is applied (a) perpendicular to and (b) parallel to c-axis. From the mid-point of the resistive curve one can determ ine the upper critical eld H $_{\rm c2}$ (T).

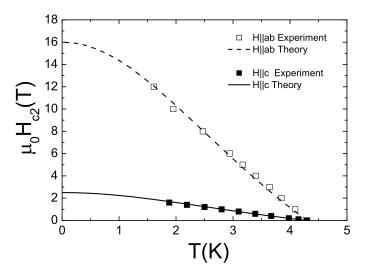


FIG.9: The upper critical eld determ ined from the midpoint of the transition curve. The solid and dashed lines here are theoretical curves of H $_{\rm c2}$ (T) = H $_{\rm c2}$ (O) [(1 t^2)=(1 + t^2)] with H $_{\rm c2}^{\rm jic}$ (0) = 2:5T and H $_{\rm c2}^{\rm jipb}$ (0) = 16T.

H $_{c2}^{jjab}(0)$ =H $_{c2}^{jjc}(0)$ = $_{ab}(0)$ = $_{c}(0)$ = $_{m_{c}=m_{ab}}^{p}$ = 6.4, where m $_{c}$ and m $_{ab}$ are the e ective mass tensors when the electrons are moving perpendicular and parallel to the TaS₂ layers. This value is quite close to that of optim ally doped Y B a₂C u₃O₇. This is to our surprise since the sample here is clearly of thin-platelet shape which looks like the much more anisotropic curate system B i₂Sr₂C aC u₂O₈ single crystals. A ctually the zero tem perature value of upper critical eld can also be determ ined through the W ertham er-H elfand-H ohenberg (W HH) form ula²⁴:

$$H_{c2}(0) = 0.693T_{c}(\frac{dH_{c2}}{dT})_{T = T_{c}}$$
 (3)

Here dH_{c2}=dT is the slope of H_{c2} (T) near T_c, which is about 0.7163 T/K for H jjc and 4.5 T/K for H jjab. Using above form ula the zero tem perature values of upper critical elds are $H_{c2}^{\rm jjc}(0) = 2.13T$ and $H_{c2}^{\rm jjab}(0) = 13.4T$, which are close to the values determined in tting the data to eq.(2).

D. Suppression to CDW by Sodium Intercalation

Trigonal prism atic layer com pound 2H TaS₂ generally exhibits a charge-density-wave related phase transition accompanied by a drop in resistivity around 70K 12 . It is thus interesting to measure the resistivity of our sam ples to high tem peratures to see whether the CDW transition is still there. We thus measured the resistivity of crystals of N $a_{0:1}$ T aS_2 from 2K to 300K . It is found that the resistivity decreases with the tem perature sm oothly and the superconducting transition happens at 4:4K, no sudden drop of resistance on the resistivity curve was observed above T_c. Fig. 10 shows the comparison of resistivity between undoped 2H TaS_2 and our sample $N a_{0:1}T aS_2$. From here it is tempting to conclude that the CDW is completely suppressed in our samples.

For further veri cation of the result obtained from $N a_{0:1}T aS_2$, we measured the resistivity of one crystal $Na_{0:05}TaS_2$ and show them in Fig.11. The CDW -like drop in resistivity curve is also com pletely absent in the tem perature region from 2K to 300K. This result provides convincing evidence that there is a competition between the superconductivity and charge density wave in layered chalcogenide N ax T aS2. W hen sodium ions are intercalated into 2H TaS₂, CDW order is destroyed and T_c increases. The suppression to the CDW may be understood by the better c-axis conduction after the sodium intercalation. In this case the system deviates from two dimensionality as in 2H TaS_2 and thus prevents the lattice instability. This is partially supported by the relatively sm all anisotropy of m $_{\rm c} = m_{\rm ab}$ as determ ined above in the sodium intercalated sam ples. W hen the CDW is suppressed, the e ective DOS at the Fermi surface is eventually enhanced leading to a much higher $T_{\rm c}$.

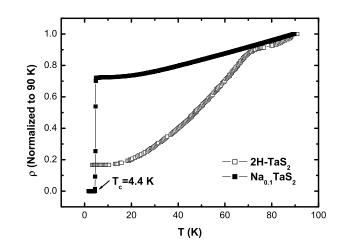


FIG.10: Comparison of resistivity between 2H TaS₂ and N a_{0:1}TaS₂. For clarity, here we show only the data from 2K to 90K. Resistivity of 2H TaS₂ is adopted from Ref.11.

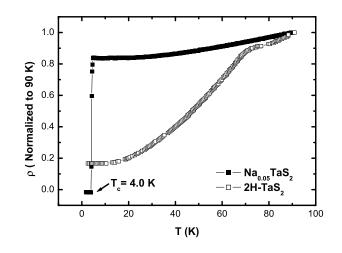


FIG.11: C om parison of resistivity between 2H T as₂ and N a_{0:05}T as₂. For clarity we show here only the data from 2K to 90K. Resistivity of 2H T as₂ is adopted from ref. 11.

E . A nisotropy of R esistivity and the C om petition betw een Superconductivity and C D W

In pyridine intercalated system s, the anisotropy of D C resistivity is in the order of 10^5 along c-axis and ab-plane. This extrem ely high anisotropy is far beyond the value we can expect in our present system . Therefore intercalating sodium here m ay enhance the electrical conduction along c-axis and suppress the feature of two dimensionality. To check whether this is true, we measured the inplane and o -plane resistivity for two samples, one with x=0.10 and $T_{\rm c}=4.2{\rm K}$, and another with x=0.05 and $T_{\rm c}=2.5{\rm K}$ (determ ined as the mid-point of the resistive

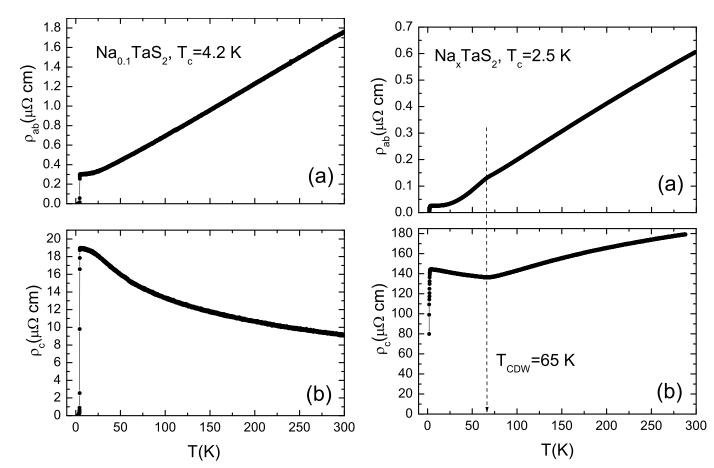


FIG. 12: Tem perature dependence of (a) in-plane and (b) o -plane resistivity for the sam ple N a_{0:1}T aS₂. One can see that the in-plane resistivity shows a metallic behavior, but the o -plane one has an insulating behavior above T_c. The anisotropy of resistivity is about 63.6 at 10K and 5.3 at 300K. On both curves we cannot see any trace of CDW . A linear behavior of the in-plane resistivity is observed in wide tem perature range. This resembles that in optim ally doped high-T_c cuprate superconductors.

transition). In Fig.12, we present the tem perature dependence of the (a) in-plane and (b) o -plane resistivity for the sample with x = 0.10 and $T_c = 4.2K$. No any trace ofCDW can be observed here. Furtherm ore, one can easily see that the tem perature dependence of the in-plane resistivity for this sample is rather linear in quite wide tem perature region. This result has been repeated in all our sam ples with T_c higher than 4 K. This behavior resem bles that of cuprate superconductors at optim aldoping (with the highest T_c in the same system). It remains an interesting question that whether this linear behavior observed here has any intact correlation with that in high-T_c cuprate superconductors. W e can also determ ine the anisotropy of resistivity for this sample at di erent tem peratures. It is found that c = ab is about 63.6 at 10K and 5.3 at 300K. Surprisingly the o -plane resistivity shows a clear sem iconducting behavior indicating totally di erent electron conduction behavior when current

FIG.13: Tem perature dependence of (a) in-plane and (b) o -plane resistivity of a sam ple N $a_{\rm x} T \, aS_2$ with x 0.05 and $T_{\rm c}=2.5K$. A clear kink corresponding to the CDW transition can be seen here. One can also see that the in-plane resistivity shows m etallic behavior in wide region of tem perature, but the o -plane resistivity rst shows a metallic behavior above $T_{C\,D\,W}$ and an insulating behavior below $T_{C\,D\,W}=65K$. The anisotropy of resistivity is about 5000 at 10K and 300 at 300K .

is owing along the plane or perpendicular to it. This interesting weak sem iconducting behavior of c-axis resistivity has also been repeated in our samples with high T_c. A ccom panying with this sem iconducting behavior, a c-axis lattice modulation (with the modulation spacing of about 4c) has been observed only in these sam ples with high T_c. Detailed analysis about the correlation with the resistive transport property, CDW and superconductivity is under way and will be published separately. For the 0:05 and $T_c = 2:5K$), the less intercalated sample (x situation becom es very di erent. As shown in Fig.13(a) and (b), one can see that a CDW transition occurs at about 65K . W orthy of noting here is the much higher anisotropy of the resistivity. One can see that c = ab is about 5000 at 10K and 300 at 300K. The anisotropy of resistivity in this less intercalated sample is about 60 to 100 times higher than that in the more intercalated sam ple (x = $0:1; T_c = 4:2K$) although a metallic behavior is

observed above T_{CDW} in these less intercalated samples. The much more higher anisotropy in these less intercalated samples may also interpret why the CDW appears in this sample. The strange metal-insulator (M-I) transition of the o -plane resistivity at T_{CDW} in the present sam ple is a very interesting issue and the discussion on it m ay exceed the scope of this paper. It must be mentioned that this M-I transition can only be observed in relatively thick samples (above 0.2 m). In rather thin samples, the c-axis resistivity shows the similar behavior of the inplane resistivity without showing the M-I transition at the T_{CDW} . We attribute the disappearance of the M-I transition to the signi cant in-plane component of the total voltage drop on the two voltage leads attached to the two opposite surfaces if the leads are slightly asymmetric. Detailed analysis and discussion of the tem perature dependence of resistivity for samples with system atic intercalated N a content will be presented in a forthcom ing paper. We must point out that, since the thickness of the sample is very thin (typically in the scale of 0:1mm) to 0.2mm), to precisely measure the o -plane resistivity is really a problem. Thus it may subject to corrections in the future with more re ned measurements. However the correction, if any in the future, will be within the range of about 20%, especially for the in-plane resistivity. In addition, we believe that the general tem perature dependence of resistivity m easured here will not be altered too much. Therefore the resistive data measured here may provide an useful platform for further understanding the interplay between CDW and superconductivity. A though we are not sure why the slight intercalation of N a can change the anisotropy and the electronic behavior so drastically, it may be safe to conclude that the higher an isotropy in the sample with less N a content enhances the 2D behavior and thus favors the structural

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instability leading to the CDW transition. This consequently suppresses the elective DOS at $E_{\rm F}$ and lowers the superconducting transition temperature.

IV. CONCLUSION

A new way to grow crystals of N $a_x T a S_2$ is presented. A series of crystals with di erent superconducting transition temperatures T_c ranging from 2.5 K to 4.4 K were obtained. It is found that T_c rises with the increase of N a content determ ined from the EDX of SEM . Compared with the resistivity curve of 2H TaS₂ (T_c $= 0.8 \text{ K}, T_{CDW}$ 70 K), no signal of charge density wave (CDW) was observed in our present samples $N a_{0:1}TaS_2$ and $N a_{0:05}TaS_2$. The upper critical eld and its anisotropy (about 6.4 for sample with x = 0.1 and $T_c = 4.2K$) have also been determ ined. The anisotropy of resistivity is strongly suppressed together with the missing of the CDW in samples with higher ${\tt T}_{\tt c}$ and more N a content. In samples with less N a content and lower T_c, the CDW can be easily observed. It is concluded that there is a competition between the superconductivity and the CDW order: The rise of T_c in N a_x T aS₂ by increasing the sodium content may be caused by the increase of DOS at Ferm i surface when the CDW is suppressed. A cknow ledgem ents This work is supported by the National Science Foundation of China, the M inistry of Science and Technology of China, and the Chinese A cadem y of Science within the know ledge innovation project. The authors are grateful to C.H.W ang, W.W.Huang and S.L. Jia for technical assistance and helpful discussions about som e measurements. The authors thank Huan Yang for helping to transform the graph form .

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